

The listing below of the claims presents in amended form claims 1 through 9 that were approved by the International Preliminary Examination Authority and that were determined to satisfy the PCT patentability criteria in the international phase of the corresponding PCT application. Claims 8 and 9 are new claims that are also based upon the approved PCT claims. The following claims replace all prior versions and listings of claims in the present application:

Listing of Claims:

Claim 1 (currently amended): A method of producing a heating element that is comprised containing essentially of molybdenum silicide and alloys of this basic material thereof, which forms aluminium aluminum oxide on its surface, characterised by said method comprising the steps of: producing a material that contains substantially Mo(Si_{1-x} Al_x)₂ and Al₂O₃ by mixing a mixture of a silicon and a molybdenum compound with an aluminium aluminum compound; in that wherein the silicon and molybdenum compound either include mixture includes Mo(Si_{1-y} Al_y)₂ and are is mixed with either an aluminium aluminum compound consisting including at least one of Al₂O₃ or Al(OH)₃ and possibly mixed with one or more of the compounds SiO₂; Si and MoO₃ or by virtue of the mixture of the silicon and molybdenum compound containing MoO₃ and Al and Si and/or SiO₂; in that wherein the input mixture components together have a degree of purity corresponding to at least 98%; and in that reacting the mixture is caused to react

exothermically and/or by being sintered components by at least on e of exothermic reaction and sintering so that exchange reactions are caused to take place [[,]] to form the compounds Mo(Si_{1-x} Al_x)₂ and Al₂O₃, where x is caused to lie lies in the range of 0.4 - 0.6.

Claim 2 (currently amended): A method according to Claim 1, characterised in that said wherein SiO₂ is included in silicates, such as mullite and sillimanite, which do the mixture is a silicate and does not effect the affect symmetry of the crystal lattice of molybdenum silicide crystal lattice.

Claim 3 (currently amended): A method according to Claim 1 er 2, characterised in that , wherein x is caused to lie lies in the range of 0.45 - 0.55.

Claim 4 (currently amended): A method according to Claim 1 2 or 3, characterised by , including the step of adding at least one or more of the following sintering auxiliaries MgO, CaO, SiO₂ and Y₂O₃ to said mixture.

Claim 5 (currently amended): A method according to Claim 1 $\frac{2}{3}$ or $\frac{4}{3}$ or $\frac{4}{3}$

Claim 6 (currently amended): A method according to Claim 5, characterised by including the step of replacing molybdenum with W in an amount corresponding to approximately one third.

Claim 7 (currently amended): A method according to any one of the preceding Claims, characterised in that claim 1, wherein the heating element input components have a degree of purity of at least 99%.

Claim 8 (new): A method according to claim 1, including the step of adding to the mixture at least one of the compounds SiO₂, Si, and MoO₃.

Claim 9 (new): A method according to claim 1, wherein the mixture of the silicon and the molybdenum compound contains MoO₃ and Al, and at least one of Si and SiO₂.

Claim 10 (new): A method according to claim 2, wherein the silicate is mullite.

Claim 11 (new): A method according to claim 2, wherein the silicate is sillimanite.